

RELIABILITY REPORT

FOR

MAX242CWN+

PLASTIC ENCAPSULATED DEVICES

October 2, 2009

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Approved by	
Ken Wendel	
Quality Assurance	
Director, Reliability Engineering	



Conclusion

The MAX242CWN+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX220-MAX249 family of line drivers/receivers is intended for all EIA/TIA-232E and V.28/V.24 communications interfaces, particularly applications where ±12V is not available. These parts are especially useful in battery-powered systems, since their low-power shutdown mode reduces power dissipation to less than 5µW. The MAX225, MAX233, MAX235, and MAX245/MAX246/MAX247 use no external components and are recommended for applications where printed circuit board space is critical.



II. Manufacturing Information

A. Description/Function: +5V-Powered, Multichannel RS-232 Drivers/Receivers

B. Process: SG5

C. Number of Device Transistors:

D. Fabrication Location: Oregon E. Assembly Location: Philippines F. Date of Initial Production: Pre 1997

III. Packaging Information

A. Package Type: 18-pin SOIC (W)

B. Lead Frame: Copper

C. Lead Finish: 100% matte Tin D. Die Attach: Conductive Epoxy E. Bondwire: Gold (1.3 mil dia.) F. Mold Material: Epoxy with silica filler G. Assembly Diagram: #05-0701-0485 H. Flammability Rating: Class UL94-V0 Level 1

I. Classification of Moisture Sensitivity per

JEDEC standard J-STD-020-C

J. Single Layer Theta Ja: 105°C/W K. Single Layer Theta Jc: 22°C/W

IV. Die Information

A. Dimensions: 70 X 109 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

AI/0.5%Cu with Ti/TiN Barrier C. Interconnect:

D. Backside Metallization: None

E. Minimum Metal Width: 5.0 microns (as drawn) F. Minimum Metal Spacing: 5.0 microns (as drawn)

5 mil. Sq. G. Bondpad Dimensions: H. Isolation Dielectric: SiO₂ I. Die Separation Method: Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts: Ken Wendel (Director, Reliability Engineering)

Bryan Preeshl (Managing Director of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppmD. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (3) is calculated as follows:

$$\lambda = 1 \over MTTF$$
 = $\frac{4.05}{192 \times 4340 \times 562 \times 2}$ (Chi square value for MTTF upper limit)

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 4.2 \text{ x } 10^{-9}$$

 $\lambda = 4.2 \text{ F.I.T. (60\% confidence level @ 25°C)}$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the SG5 Process results in a FIT Rate of 0.12 @ 25C and 2.04 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The PS20-2 die type has been found to have all pins able to withstand a HBM transient pulse of +/-1000 V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250 mA.



Table 1Reliability Evaluation Test Results

MAX242CWN+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test (N	Note 1)				
	Ta = 135°C	DC Parameters	562	1	
	Biased	& functionality			
	Time = 192 hrs.				
Moisture Testing	(Note 2)				
HAST	Ta = 130°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 96hrs.				
Mechanical Stress	s (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
	Method 1010	•			

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data